



Standard Rectifier

$$V_{RRM} = 1200\text{ V}$$

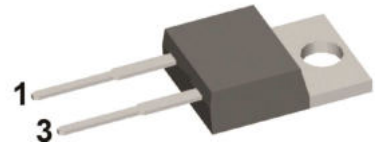
$$I_{FAV} = 30\text{ A}$$

$$V_F = 1.25\text{ V}$$

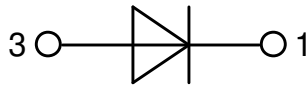
Single Diode

Part number

DSI30-12A



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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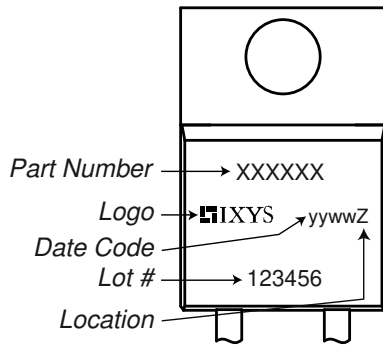


| Rectifier | | | | Ratings | | | |
|------------|--|--|---|--------------------------|------|------|------------------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V_{RSM} | max. non-repetitive reverse blocking voltage | | | | | 1300 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | | | | | 1200 | V |
| I_R | reverse current | $V_R = 1200$ V | $T_{VJ} = 25^\circ\text{C}$ | | | 40 | μA |
| | | $V_R = 1200$ V | $T_{VJ} = 150^\circ\text{C}$ | | | 1.5 | mA |
| V_F | forward voltage drop | $I_F = 30$ A | $T_{VJ} = 25^\circ\text{C}$ | | | 1.29 | V |
| | | $I_F = 60$ A | | | | 1.60 | V |
| | | $I_F = 30$ A | $T_{VJ} = 150^\circ\text{C}$ | | | 1.25 | V |
| | | $I_F = 60$ A | | | | 1.66 | V |
| I_{FAV} | average forward current | $T_C = 130^\circ\text{C}$ rectangular | $T_{VJ} = 175^\circ\text{C}$ d = 0.5 | | | 30 | A |
| V_{FO} | threshold voltage | } for power loss calculation only | | | | 0.82 | V |
| r_F | slope resistance | | | | | 14.1 | m Ω |
| R_{thJC} | thermal resistance junction to case | | | | | 0.9 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | | 0.5 | | K/W |
| P_{tot} | total power dissipation | | | $T_C = 25^\circ\text{C}$ | | 160 | W |
| I_{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^\circ\text{C}$ | | | 300 | A |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0$ V | | | 325 | A |
| | | t = 10 ms; (50 Hz), sine | $T_{VJ} = 150^\circ\text{C}$ | | | 255 | A |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0$ V | | | 275 | A |
| I^2t | value for fusing | t = 10 ms; (50 Hz), sine | $T_{VJ} = 45^\circ\text{C}$ | | | 450 | A ² s |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0$ V | | | 440 | A ² s |
| | | t = 10 ms; (50 Hz), sine | $T_{VJ} = 150^\circ\text{C}$ | | | 325 | A ² s |
| | | t = 8,3 ms; (60 Hz), sine | $V_R = 0$ V | | | 315 | A ² s |
| C_J | junction capacitance | $V_R = 400$ V; f = 1 MHz | $T_{VJ} = 25^\circ\text{C}$ | | 10 | | pF |



| Package TO-220 | | | Ratings | | | |
|----------------|------------------------------|--------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 35 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 175 | °C |
| T_{op} | operation temperature | | -40 | | 150 | °C |
| T_{stg} | storage temperature | | -40 | | 150 | °C |
| Weight | | | | 2 | | g |
| M_D | mounting torque | | 0.4 | | 0.6 | Nm |
| F_C | mounting force with clip | | 20 | | 60 | N |

Product Marking



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSI30-12A | DSI30-12A | Tube | 50 | 476390 |

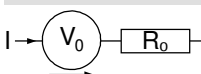
| Similar Part | Package | Voltage class |
|--------------|----------------------|---------------|
| DSI30-08A | TO-220AC (2) | 800 |
| DSI30-08AS | TO-263AB (D2Pak) (2) | 800 |
| DSI30-08AC | ISOPLUS220AC (2) | 800 |
| DSI30-12AS | TO-263AB (D2Pak) (2) | 1200 |

| | | |
|------------|----------------------|------|
| DSI30-12AC | ISOPLUS220AC (2) | 1200 |
| DSI30-16A | TO-220AC (2) | 1600 |
| DSI30-16AS | TO-263AB (D2Pak) (2) | 1600 |

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 175^{\circ}\text{C}$

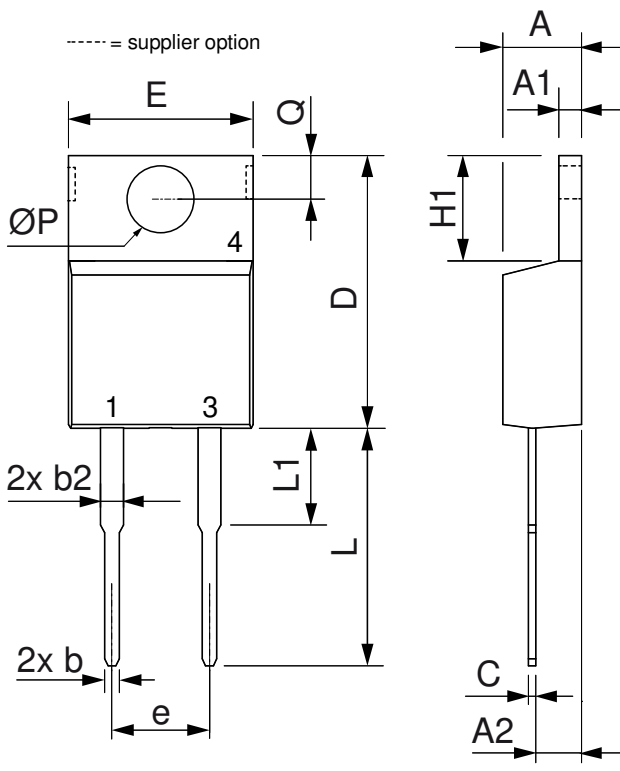


Rectifier

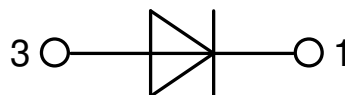
| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 0.82 | V |
| $R_{0\ max}$ | slope resistance * | 11 | mΩ |



Outlines TO-220



| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.32 | 4.82 | 0.170 | 0.190 |
| A1 | 1.14 | 1.39 | 0.045 | 0.055 |
| A2 | 2.29 | 2.79 | 0.090 | 0.110 |
| b | 0.64 | 1.01 | 0.025 | 0.040 |
| b2 | 1.15 | 1.65 | 0.045 | 0.065 |
| C | 0.35 | 0.56 | 0.014 | 0.022 |
| D | 14.73 | 16.00 | 0.580 | 0.630 |
| E | 9.91 | 10.66 | 0.390 | 0.420 |
| e | 5.08 | BSC | 0.200 | BSC |
| H1 | 5.85 | 6.85 | 0.230 | 0.270 |
| L | 12.70 | 13.97 | 0.500 | 0.550 |
| L1 | 2.79 | 5.84 | 0.110 | 0.230 |
| ØP | 3.54 | 4.08 | 0.139 | 0.161 |
| Q | 2.54 | 3.18 | 0.100 | 0.125 |



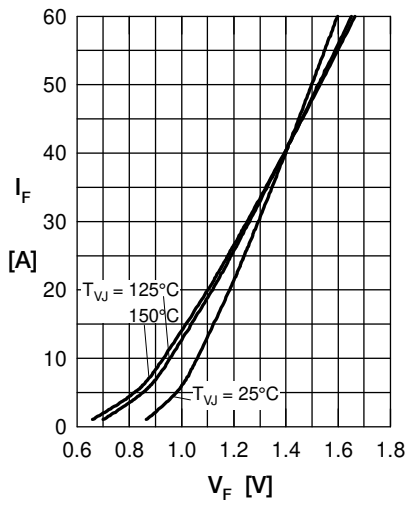
Rectifier


Fig. 1 Forward current versus voltage drop per diode

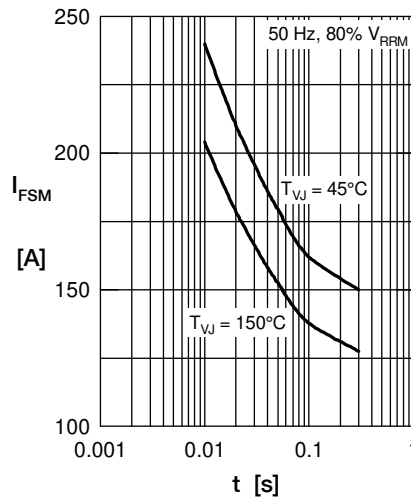


Fig. 2 Surge overload current

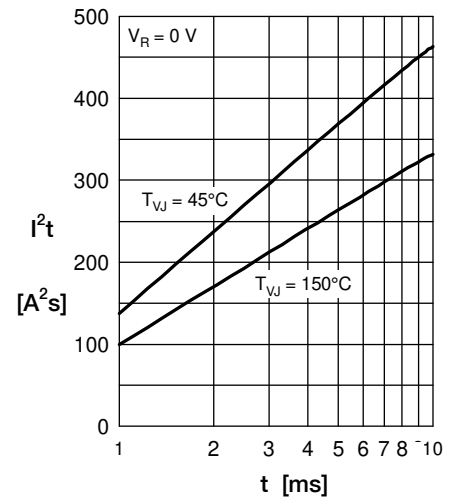
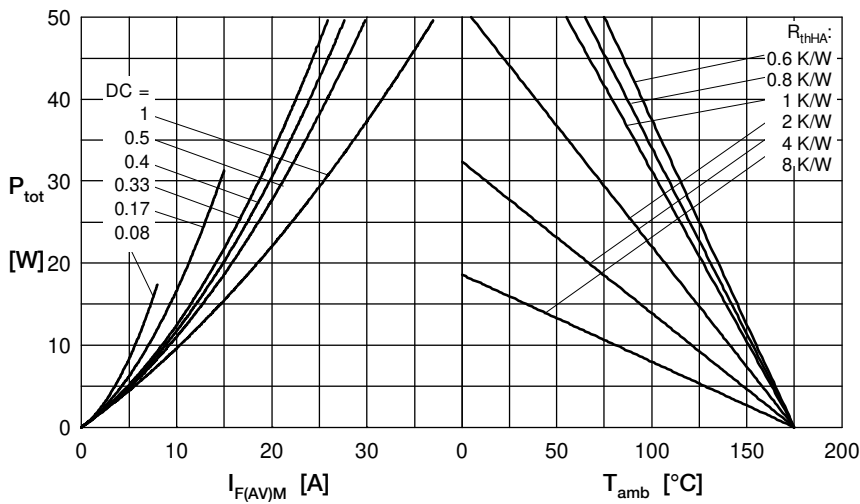

 Fig. 3 I^2t versus time per diode


Fig. 4 Power dissipation vs. direct output current and ambient temperature

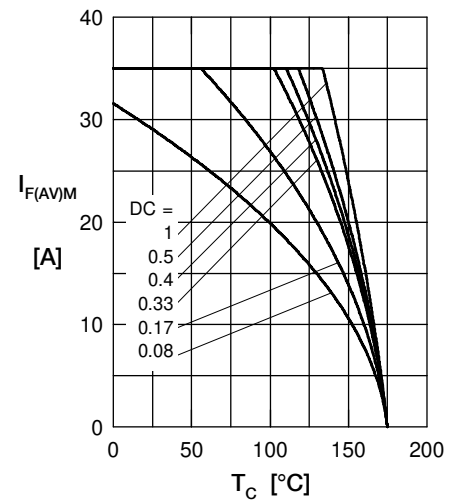


Fig. 5 Max. forward current vs. case temperature

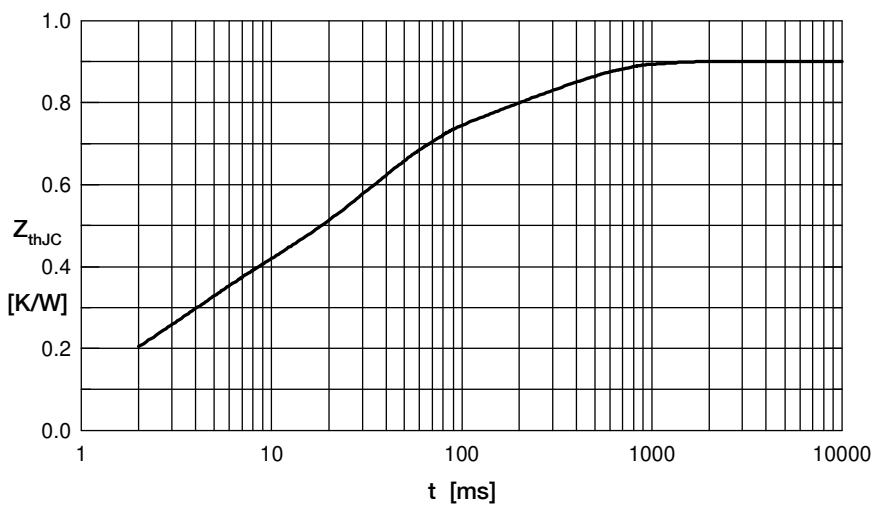


Fig. 6 Transient thermal impedance junction to case

 Constants for Z_{thJC} calculation:

| i | R_{thi} (K/W) | t_i (s) |
|---|-----------------|-----------|
| 1 | 0.03 | 0.0004 |
| 2 | 0.08 | 0.002 |
| 3 | 0.2 | 0.003 |
| 4 | 0.39 | 0.03 |
| 5 | 0.2 | 0.29 |